

Photovoltaic Solar Cell Protection Schottky Diode

Reverse Voltage - 45 Volts Forward Current - 30 Amperes

Features

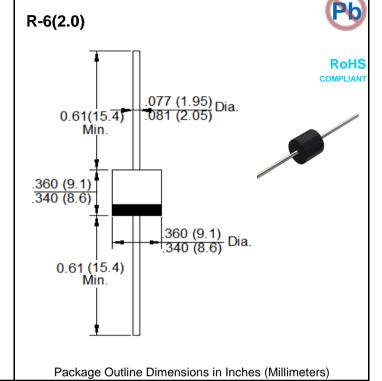
- Low power loss, high efficiency
- High current capability, low V_F
- High surge capacity

Mechanical Data

- Case: JEDEC R-6 molded plastic
- Polarity: Color band denotes cathode
- Mounting position: Any

Applications

• For use in solar cell junction box as a bypass diode



Maximum Ratings and Electrical Characteristics

Rating at 25 ℃ ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

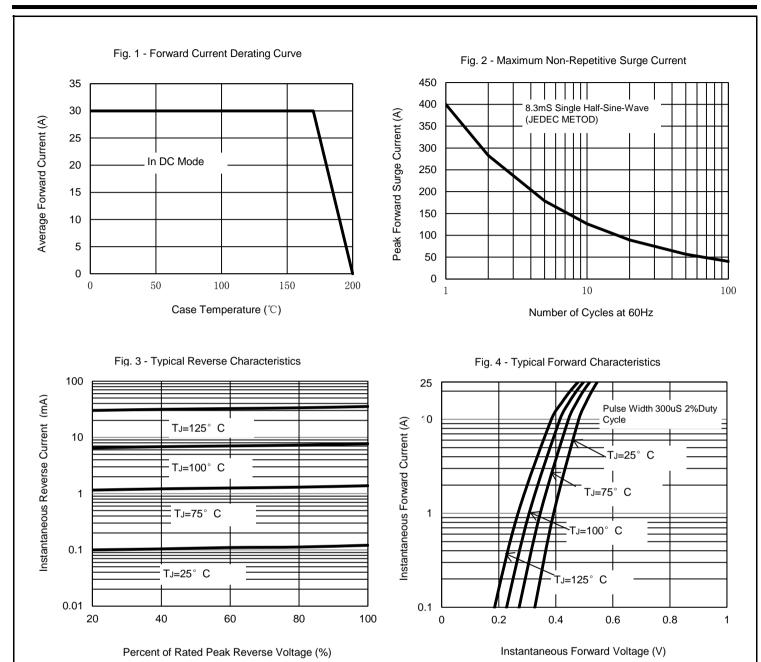
For capacitive load, derate current by 20%.

Characteristics		Symbol	30SQ045	Unit
Maximum Repetitive Peak Reverse Voltage		Vrrm	45	V
Maximum RMS Voltage		VRMS	31.5	V
Maximum DC Blocking Voltage		VDC	45	V
Maximum Average Forward Rectified Current @ Tc=170 ℃		I(AV)	30	А
Peak Forward Surge Current, 8.3mS Single Half Sine-Wave, Superimposed on Rated Load (JEDEC Method)		IFSM	400	А
Peak Forward Voltage at 30A DC (Note1)		VF	0.55	V
Maximun DC Reverse Current at Rated DC Blocking Voltage	@TJ=25℃		0.1	
	@TJ=75℃	lr	2	mA
	@TJ=125℃		35	
Typical Thermal Resistance Junction to Case		Rejc	1.5	°C/W
Junction Temperature Range		TJ	-55 to+200	°C
Storage Temperature Range		Тѕтс	-55 to+200	$^{\circ}$

Notes: 1. 300uS pulse width, 2%duty cycle.

2. The typical data above is for reference only.





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